



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	1/34
Date:	2021.01.01

- SUBJECT** : This specification applies on the chip capacitor was made by SYNTON-TECH Corporation .
- PART NUMBER** : Part number of the chip capacitor is identified by the size, dielectric, capacitance value, tolerance, voltage .

Example : **DESCRIPTION : 0402 NPO 100PF 50V J**

SYNTON CODE : 0402 NPO 101 J 50V

<u>SIZE</u>	<u>DIELECTRIC</u>	<u>CAPACITANCE</u>	<u>TOLERANCE</u>	<u>VOLTAGE</u>
0201	NPO	<u>VALUE</u>	10PF and below	6.3V
0402	X7R	3 Digits : 5R1 : 5.1pF	B : $\pm 0.10\text{PF}$	10V
0603	X5R	100 : 10pF	C : $\pm 0.25\text{PF}$	16V
0805	Y5V	101 : 100pF	D : $\pm 0.5\text{PF}$	25V
1206	Z5U	102 : 1nF		50V
1210		103 : 10nF		100V
1808		104 : 0.1uF	More than 10pF	200V
1812		105 : 1uF	F : $\pm 1\%$	250V
2220			G : $\pm 2\%$	500V
			J : $\pm 5\%$	630V
			K : $\pm 10\%$	1KV
			M : $\pm 20\%$	2KV
			Z : -20~+80%	3KV

APPROVED	CHECKED	DESIGNED	REMARK	DOCUMENT NO.
Carol	May	Chen		0201010567

	SYNTON-TECH CORPORATION	File No.:	CC-02—A-#H022
	CHIP MULTILAYER CERAMIC CAPACITOR (AEC-Q200)	Version:	A
		Page:	2/34
		Date:	2021.01.01

3. CAPACITOR CLASSIFICATION

Multi-layer ceramic capacitors are available in wide range of characteristics. Electronic Industries Association (EIA) and the military have established categories to help divide the basic characteristics into more easily specified classes. The basic industry specification for ceramic capacitor is EIA specification RS-198 and as noted in the general section, it specifies temperature-compensating capacitors as class I capacitors. These are specified by the military under specification MIL-C-20. General-purpose capacitors with non-linear temperature coefficients are called Class II capacitors by EIA and specified by military under MIL-C-11015 and MIL-C-39014. The new high reliability military specification, MIL-C-123 covers both class I and class II dielectrics.

Class I — Class I capacitors or temperature-compensating capacitors are usually made from mixtures of titanate where barium titanate is normally not a major part of mix. They have predictable temperature coefficients and in general, do not have an aging characteristic. Thus they are the most stable capacitor available. Normally the T.C.s of Class I temperature-compensating capacitors are NP0 ($\pm 30 \text{ ppm}^{\circ}\text{C}$).

Class II — General-purpose ceramic capacitors are called Class II capacitors and have become extremely popular because of the high capacitance values available in very small size. These capacitors are ferroelectrics and vary in capacitance value under the influence of the environmental and electrical operating conditions. Class II capacitors are affected by temperature、voltage、frequency and time. Temperature effects for Class II ceramic capacitors are exhibited as non-linear capacitance changes with temperature. Industry standards for Mid-K dielectrics, such as X7R, X5R and High-K dielectrics, such as Z5U and Y5V are defined as Class II formulations.



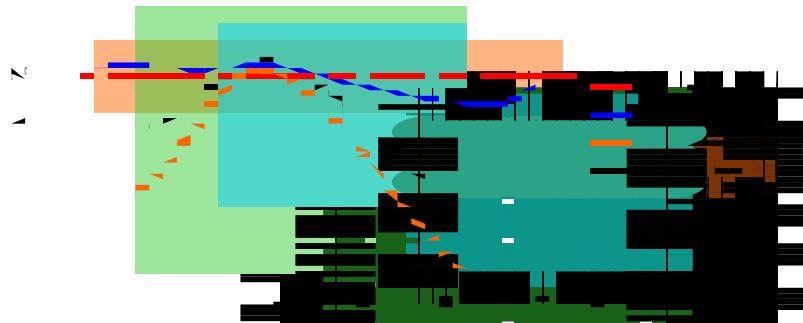
SYNTON-TECH CORPORATION

CHIP MULTILAYER CERAMIC CAPACITOR (AEC-Q200)

File No.:	CC-02-A-#H022
Version:	A
Page:	3/34
Date:	2021.01.01

4. MATERIALS AND PERFORMANCE CHARACTERIZATION

Designation	Class	Temperature Range (°C)	Temp-Cap Change
Temperature compensating NPO,COG	I	-55 ~ +125	± 30 ppm/°C
Intermediate K X7R, BX	II	-55 ~ +125	± 15 %
Intermediate K X5R	II	-55 ~ +85	± 15 %
High K Y5V	II	-25 ~ +85	+22 ~ -82 %
High K Z5U	II	+10 ~ +85	+22 ~ -56 %



The T.C curve of each material. (for reference)

5. TECHNOLOGY

Multi-layer ceramic capacitor constructed by depositing alternative layers of ceramic dielectric materials and internal metallic electrodes, by advanced ceramic manufacturing technology, and co-firing into an indestructible homogeneous body, then completed with application of metal end terminations which are fired on to assure that permanent connection of individual internal electrodes are in parallel.

The terminations also can be nickel-plated and then solder plated to give the chip capacitors nickel-barrier terminations which have much better leaching resistance during soldering.

Reliable performances are built-in through exact formulation of dielectric powders, preparation of conductive paste, advanced automatic manufacturing, and strict quality control to assure excellent control in dielectric thickness, electrode integrity, and electrode-to-termination continuity.



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	4/34
Date:	2021.01.01

6. ELECTRICAL CHARACTERISTICS

NPO

Characterizes	Test conditions	Requirement
Operation temp. range		-55°C ~ +125°C
Temp. coefficient (TC)	With respect to 25°C within operation temp. range	C<10pF, ±150ppm/°C C≥10pF, ±30ppm/°C
Capacitance tol.	Class I : (NPO)	In accordance with spec.
Dissipation Factor (Tan δ)	<1000pF 1.0±0.2Vrms, 1MHz±10% >1000pF 1.0±0.2Vrms, 1KHz±10%	C<10pF Tan δ≤10(3/C+0.7)×10E-4 or 30×10E-4 whichever is less C≥10pF Tan δ≤10×10E-4
Insulation Resistance (IR)	V _r (rated voltage)≤500V At V _r for 1 minute V _r (rated voltage)≤500V At 500V for 1 minute	Rins > 100GΩ or Rins × C ≥ 500Ω·F whichever is less
Dielectric withstand voltage	V _r (rated voltage)≤ 100V At 2.5V _r for 5 seconds V _r (rated voltage)=200/250V At 2.0V _r +100V for 5 seconds V _r (rated voltage)≥ 500V At 1.5V _r for 5 seconds	No breakdown

X7R/X5R/Y5V

Characterizes	Test conditions	Requirement		
		X7R	X5R	Y5V
Operation temp. range		-55°C ~ +125°C	-25°C ~ +85°C	-25°C ~ +85°C
Temp. coefficient (TC)	X7R/X5R: With respect to 25°C within operation temp. range Y5V: With respect to 20°C within operation temp. range	±15%	±15%	+30%~-80%
Capacitance tol.		In accordance with spec.		
Dissipation Factor (Tan δ)	Class II : (X7R,X5R,Y5V) C≤10uF 1.0±0.2Vrms, 1KHz±10% C>10uF 0.5±0.2Vrms, 120Hz±20%	50V Tan δ≤ 2.5% 25V/16V Tan δ≤ 3.5% 10V Tan δ≤ 5% 6.3V Tan δ≤10%	50V Tan δ≤ 2.5% 25V/16V Tan δ≤ 3.5% 10V Tan δ≤ 5% 6.3V Tan δ≤10%	50V/25V Tan δ≤ 5% 16V(C<1uF) Tan δ≤ 7% 16V(C≥1uF) Tan δ≤ 9% 10V Tan δ≤ 12.5%
Insulation Resistance (IR)	V _r (rated voltage)≤500V At V _r for 1 minute V _r (rated voltage)≤500V At 500V for 1 minute	Rins > 10GΩ or R × C ≥ 100Ω · F Whichever is less	Rins > 10GΩ or R × C ≥ 100Ω · F Whichever is less	Rins > 10GΩ or R × C ≥ 100Ω · F Whichever is less

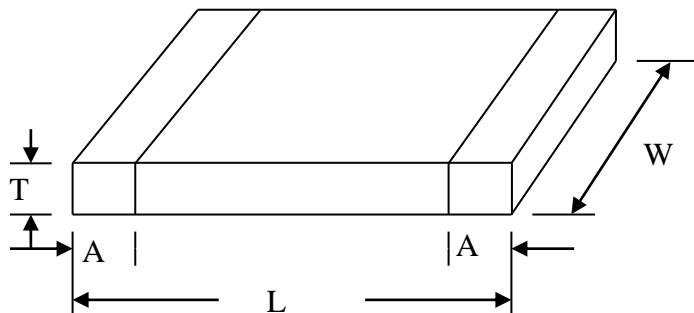


SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	5/34
Date:	2021.01.01

Dielectric withstand voltage	V _r (rated voltage) ≤ 100V At 2.5V _r for 5 seconds V _r (rated voltage) = 200/250V At 2.0V _r +100V for 5 seconds V _r (rated voltage) ≥ 500V At 1.5V _r for 5 seconds	No breakdown
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7. DIMENSION



Unit:mm

Case size	Length (L)	Width (W)	Thickness (T)	Termination length (A)
0201	0.60±0.03	0.30±0.03	0.30±0.03	0.10~0.20
0402	1.0±0.05	0.50±0.05	0.50±0.05	0.15~0.35
0603	1.6±0.15	0.80±0.15	0.65~0.95	0.25~0.65
0805	2.0±0.20	1.25±0.20	0.40~1.55	0.25~0.75
1206	3.2±0.30	1.60±0.30	0.50~1.95	0.35~0.85
1210	3.2±0.40	2.5±0.30	0.80~2.90	0.45~1.00
1808	4.6±0.40	2.00±0.30	1.00~2.90	0.45~1.00



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	6/34
Date:	2021.01.01

1812	4.6±0.40	3.20±0.30	1.00~3.20	0.45~1.00
2220	5.7±0.40	5.00±0.40	1.80~3.00	0.30~1.00

8. ENVIRONMENTAL AND TEST CHARACTERISTICS

Test item	Conditions	Requirements
Capacitance	NPO/X7R: measuring voltage 1 V at 25°C Y5V/Z5U: measuring voltage 1 V at 25°C $C \leq 1000 \text{ pF}, f = 1 \text{ MHz};$ $C > 1000 \text{ pF}, f = 1 \text{ kHz};$	Within specified tolerance
$\tan \delta$	Class I : (NPO) $<1000\text{pF} \quad 1.0 \pm 0.2\text{Vrms}, 1\text{MHz} \pm 10\%$ $>1000\text{pF} \quad 1.0 \pm 0.2\text{Vrms}, 1\text{KHz} \pm 10\%$ Class II : (X7R,X5R,Y5V) $C \leq 10\mu\text{F} \quad 1.0 \pm 0.2\text{Vrms}, 1\text{KHz} \pm 10\%$ $C > 10\mu\text{F} \quad 0.5 \pm 0.2\text{Vrms}, 120\text{Hz} \pm 20\%$	In accordance with specification
Insulation resistance	To apply rated voltage for max. 120sec.	$10\text{G}\Omega$ or $R_x C \geq 500\Omega\cdot\text{F}$ whichever is smaller. Class II (X5R, X7R, Y5V) Rated voltage* 10V: 0603>0.47uF; 0805>2.2uF 1206>4.7uF * 6.3V Insulation Resistance $\geq 100\Omega\cdot\text{F}$
	Rated voltage: 200~630V To apply rated voltage(500V max) for 60sec	$\geq 10\text{G}\Omega$ OR $100\Omega\cdot\text{F}$ whichever is smaller.
	Rated voltage: >630V To apply 500V for 60 sec	$\geq 10\text{G}\Omega$ OR $100\Omega\cdot\text{F}$ whichever is smaller.
Voltage proof	V_r (rated voltage) $\leq 100\text{V}$ At 2.5 V_r for 5 seconds, 50mA V_r (rated voltage) = 200/250V At 1.5 V_r +100V for 5 seconds, 50mA V_r (rated voltage) $\geq 500\text{V}$ At 1.2 V_r for 5 seconds, 50mA	No breakdown No flashover
Adhesive Strength of Termination	Pressurizing force: 0201:2N 0402&0603:5N >0603:10N* test time: 10 ± 1 sec.	No visible damage



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	7/34
Date:	2021.01.01

Bending Test	*The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1 mm per second until the deflection becomes 1 mm and then the pressure shall be maintained for 5 ± 1 sec. *Measurement to be made after keeping at room temp. for 24 ± 2 hrs.	No remarkable damage. Cap change: NPO: within ± 5.0 % or ± 0.5 pF whichever is larger. X7R,X5R : within ± 12.5 % Y5V: within ± 30 % (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)
Resistance to soldering heat	$260 \pm 5^\circ\text{C}$ for $10 + 0.5$ s	The terminations must be well tinned, after recovery. NPO: $\Delta C/C \leq 25$ % or ± 0.25 pF whichever is larger. X7R/X5R: Within $\pm 7.5\%$ Y5V: Within $\pm 20\%$
Resistance to leaching	$260 \pm 5^\circ\text{C}$ for 30 ± 1 s in static solder bath	With visual enlargement of x 10, dissolution of the terminations should not exceed 10 %
Solderability	Zero hour test, and test after storage (20 to 24 months) in original atmosphere in normal atmosphere; un-mounted chips completely immersed for 2 ± 0.5 s in a solder bath of $235 \pm 5^\circ\text{C}$.	95% Min. coverage of all metallized area.
Temperature Cycle	NPO/X7R: -55°C to $+125^\circ\text{C}$, 5 cycle Y5V: -25°C to $+85^\circ\text{C}$, 5 cycle X5R: -55°C to $+85^\circ\text{C}$, 5 cycle Duration: 30 mins. Recovery: 24 ± 2 hrs.	No visible damage after 24 hrs recovery Class I NPO: $\Delta C/C \leq 2.5$ % or 0.25 pF X7R/X5R: $\Delta C/C \leq \pm 7.5$ % Y5V/Z5U: $\Delta C/C \leq \pm 20$ %



SYNTON-TECH CORPORATION

**CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02—A-#H022
Version:	A
Page:	8/34
Date:	2021.01.01

**Humidity
(Steady State)**

Test temp.: $40 \pm 2^\circ\text{C}$
 Humidity : 90 to 95 % RH
 Test time 500+24/-0hrs.
 Measurement to be made after keeping at room temp. for 24 ± 2 hrs.(ClassI) or 48 ± 4 hrs.(ClassII).

No remarkable damage.

Cap change:

NPO: within $\pm 5.0\%$ or $\pm 0.5\text{pF}$ whichever is larger.
 X7R/X5R: $\geq 10\text{V}$,within $\pm 12.5\%$, 6.3V ,within $\pm 25\%$

TT series & Cap $\geq 1\mu\text{F}$, within $\pm 25\%$

Y5V: $\geq 10\text{V}$, within $\pm 30\%$, 6.3V , within $+30/-40\%$

Q/D. F. value :

NPO: More than 30pF $Q \geq 350$, $10\text{pF} \leq C < 30\text{pF}$,
 $Q \geq 275 + 2.5\text{C}$
 Less than 10pF $Q \geq 200 + 10\text{C}$

X7R/X5R:

Rated vol.	D.F. \leq	Exception D.F. \leq	
$\geq 50\text{V}$	$\leq 3\%$	$\leq 6\%$	0201(50V) 0603$\geq 0.047\mu\text{F}$ 0805$\geq 0.18\mu\text{F}$ 1206$\geq 0.47\mu\text{F}$
	$\leq 5\%$	$\leq 20\%$	0603$\geq 1.0\mu\text{F}$ 0805&1206$\geq 2.2\mu\text{F}$ 1210$\geq 10\mu\text{F}$
	$\leq 5\%$	$\leq 10\%$	0805$\geq 1\mu\text{F}$ 1210$\geq 10\mu\text{F}$
		$\leq 14\%$	0603$\geq 0.33\mu\text{F}$ 1206$\geq 4.7\mu\text{F}$
25V		$\leq 15\%$	0603$\geq 0.47\mu\text{F}$ 0805$\geq 2.2\mu\text{F}$ 1206$\geq 6.8\mu\text{F}$
$\leq 5\%$	$\leq 10\%$	0603$\geq 0.15\mu\text{F}$ 0805$\geq 0.68\mu\text{F}$ 1206$\geq 2.2\mu\text{F}$ 1210$\geq 4.7\mu\text{F}$	
	$\leq 15\%$	0603$\geq 0.68\mu\text{F}$ 0805$\geq 2.2\mu\text{F}$ 1206$\geq 4.7\mu\text{F}$	
10V	$\leq 7.5\%$	$\leq 15\%$	0603$\geq 0.33\mu\text{F}$ 0805$\geq 2.2\mu\text{F}$ 1206$\geq 2.2\mu\text{F}$ 1210$\geq 22\mu\text{F}$
		$\leq 15\%$	0402$\geq 1.0\mu\text{F}$ 0603$\geq 10\mu\text{F}$ 0805$\geq 4.7\mu\text{F}$ 1210$\geq 100\mu\text{F}$
6.3V	$\leq 15\%$	$\leq 30\%$	



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	9/34
Date:	2021.01.01

Y5V:

Rated vol.	D.F.≤	Exception D.F.≤	
≥50V	≤7.5%	≤10%	0603≥0.1uF; 0805≥0.47uF;
35V	≤10%		
25V	≤7.5%	≤10%	0402≥0.047uF; 0603≥0.1uF; 0805≥0.33uF; 1206≥1uF; 1210≥4.7uF;
		≤15%	0402≥0.068uF; 0603≥0.47uF; 1206≥4.7uF;
16V (C<1.0uF)	≤10%	≤125%	0402≥0.068uF; 0603≥0.68uF;
16V (C<1.0uF)	≤125%	≤20%	0805≥4.7uF; 1206≥10uF; 1210≥22uF; 1812≥47uF; TT series&Cap≥1uF
10V	≤20%		
6.3V	≤30%		

*I.R.:≥10V 1GΩ or 50Ω·F whichever is smaller
6.3V 1GΩ·F



SYNTON-TECH CORPORATION

**CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02—A-#H022
Version:	A
Page:	10/34
Date:	2021.01.01

High Temperature Load (Endurance)	<p>No remarkable damage.</p> <p>Cap change: NPO: within $\pm 3.0\%$ or $\pm 0.3\text{pF}$ whichever is larger. X7R/X5R: $\geq 10\text{V}$, within $\pm 12.5\%$, 6.3V, within $\pm 25\%$ TT series & Cap $\geq 1\mu\text{F}$, within $\pm 25\%$ Y5V: $\geq 10\text{V}$, within $\pm 30\%$, 6.3V, within $+30$ to -40%</p> <p>Q/D.F. value: NPO: Cap $\geq 30\text{pF}$, Q ≥ 350, $10\text{pF} \leq \text{Cap} < 30\text{pF}$, Q $\geq 275+2.5\text{C}$ Cap $< 10\text{pF}$, Q $\geq 200+10\text{C}$</p> <p>X7R/X5R:</p> <table border="1"> <thead> <tr> <th>Rated vol.</th><th>D.F.≤</th><th>Exception D.F.≤</th></tr> </thead> <tbody> <tr> <td>$\geq 50\text{V}$</td><td>$\leq 3\%$</td><td>$\leq 6\%$ 0201(50V); 0603$\geq 0.047\mu\text{F}$; 0805$\geq 0.18\mu\text{F}$; 1206$\geq 0.47\mu\text{F}$;</td></tr> <tr> <td>35V</td><td>$\leq 5\%$</td><td></td></tr> <tr> <td rowspan="3">25V</td><td rowspan="3">$\leq 5\%$</td><td>$\leq 10\%$ 0805$\geq 1\mu\text{F}$; 1206$\geq 1\mu\text{F}$; 1210$\geq 10\mu\text{F}$;</td></tr> <tr> <td>$\leq 14\%$ 0402$\geq 0.10\mu\text{F}$; 0603$\geq 0.33\mu\text{F}$; 0805$\geq 2.2\mu\text{F}$; 1206$\geq 4.7\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$</td></tr> <tr> <td>$\leq 15\%$ 0603$\geq 0.68\mu\text{F}$; 0805$\geq 4.7\mu\text{F}$; 1206$\geq 6.8\mu\text{F}$;</td></tr> <tr> <td rowspan="3">16V</td><td rowspan="3">$\leq 5\%$</td><td>$\leq 10\%$ 0402$\geq 0.033\mu\text{F}$; 0603$\geq 0.15\mu\text{F}$; 0805$\geq 0.68\mu\text{F}$; 1206$\geq 2.2\mu\text{F}$; 1210$\geq 4.7\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$</td></tr> <tr> <td>$\leq 15\%$ 0603$\geq 0.68\mu\text{F}$; 0805$\geq 2.2\mu\text{F}$; 1206$\geq 6.8\mu\text{F}$; 1210$\geq 22\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$</td></tr> <tr> <td>$\leq 7.5\%$ 0603$\geq 0.33\mu\text{F}$; 0805$\geq 2.2\mu\text{F}$; 1206$\geq 2.2\mu\text{F}$; 1210$\geq 22\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$</td></tr> <tr> <td>6.3V</td><td>$\leq 15\%$</td><td>$\leq 30\%$ 0402$\geq 2.2\mu\text{F}$; 0603$\geq 10\mu\text{F}$; 0805$\geq 10\mu\text{F}$; 1210$\geq 100\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$</td></tr> </tbody> </table>	Rated vol.	D.F.≤	Exception D.F.≤	$\geq 50\text{V}$	$\leq 3\%$	$\leq 6\%$ 0201(50V); 0603 $\geq 0.047\mu\text{F}$; 0805 $\geq 0.18\mu\text{F}$; 1206 $\geq 0.47\mu\text{F}$;	35V	$\leq 5\%$		25V	$\leq 5\%$	$\leq 10\%$ 0805 $\geq 1\mu\text{F}$; 1206 $\geq 1\mu\text{F}$; 1210 $\geq 10\mu\text{F}$;	$\leq 14\%$ 0402 $\geq 0.10\mu\text{F}$; 0603 $\geq 0.33\mu\text{F}$; 0805 $\geq 2.2\mu\text{F}$; 1206 $\geq 4.7\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$	$\leq 15\%$ 0603 $\geq 0.68\mu\text{F}$; 0805 $\geq 4.7\mu\text{F}$; 1206 $\geq 6.8\mu\text{F}$;	16V	$\leq 5\%$	$\leq 10\%$ 0402 $\geq 0.033\mu\text{F}$; 0603 $\geq 0.15\mu\text{F}$; 0805 $\geq 0.68\mu\text{F}$; 1206 $\geq 2.2\mu\text{F}$; 1210 $\geq 4.7\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$	$\leq 15\%$ 0603 $\geq 0.68\mu\text{F}$; 0805 $\geq 2.2\mu\text{F}$; 1206 $\geq 6.8\mu\text{F}$; 1210 $\geq 22\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$	$\leq 7.5\%$ 0603 $\geq 0.33\mu\text{F}$; 0805 $\geq 2.2\mu\text{F}$; 1206 $\geq 2.2\mu\text{F}$; 1210 $\geq 22\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$	6.3V	$\leq 15\%$	$\leq 30\%$ 0402 $\geq 2.2\mu\text{F}$; 0603 $\geq 10\mu\text{F}$; 0805 $\geq 10\mu\text{F}$; 1210 $\geq 100\mu\text{F}$; TT series&Cap $\geq 1\mu\text{F}$
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SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	11/34
Date:	2021.01.01

Y5V:

Rated vol.	D.F.≤	Exception D.F.≤
25V	≤7.5%	0402≥0.047uF; 0603≥0.1uF; 0805≥0.33uF; 1206≥1uF; 1210≥4.7uF;
		0402≥0.068uF; 0603≥0.47uF; 1206≥4.7uF;
16V (C<1.0uF)	≤10%	0402≥0.068uF; 0603≥0.68uF;
		0805≥3.3uF; 1206≥10uF; 1210≥22uF; 1812≥47uF; TT series&Cap≥1uF
10V	≤20%	
6.3V	≤30%	

*I.R.:≥10V 1GΩ or 50Ω-F whichever is smaller
6.3V 1GΩ-F



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

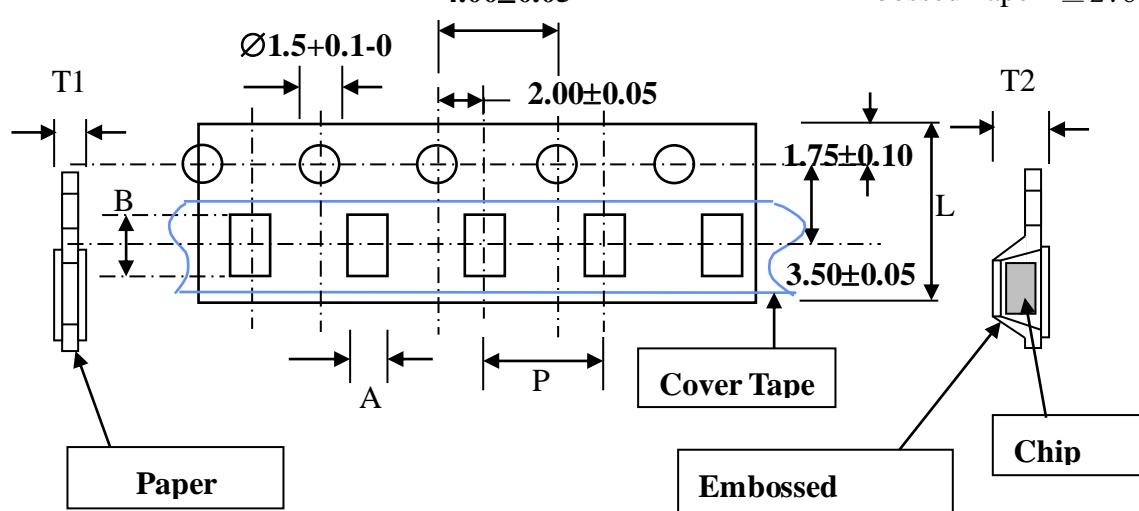
File No.:	CC-02-A-#H022
Version:	A
Page:	12/34
Date:	2021.01.01

9. PACKING

Paper Tape T ≤ 1.1 mm

4.00±0.05

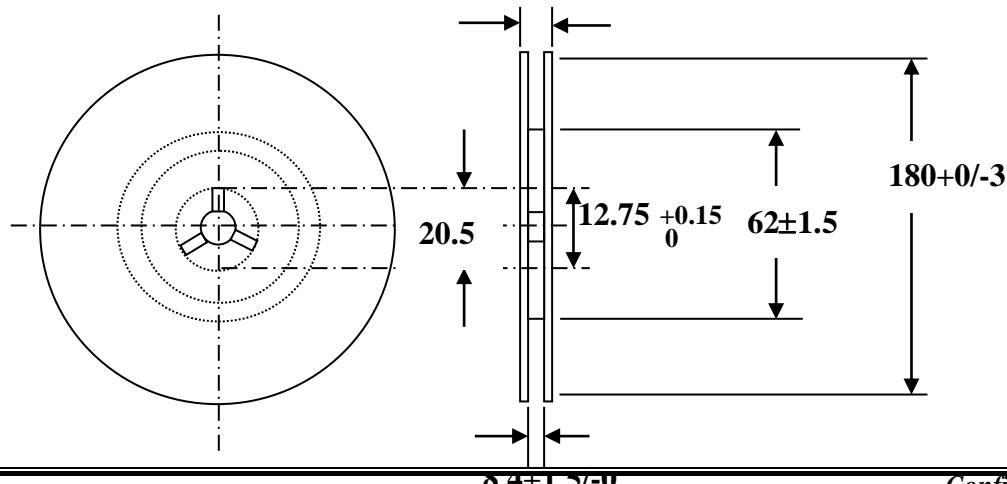
Embossed Tape T ≤ 2.60



Unit:mm

Symbol	Pocket Size Code								
	0201	0402	0603	0805	1206	1210	1808	1812	2220
A	0.37±0.03	0.62±0.05	1.10±0.10	1.65±0.05	2.00±0.10	2.80±0.20	2.50±0.30	3.60±0.30	MAX5.8
B	0.67±0.03	1.12±0.05	1.90±0.10	2.40±0.05	3.50±0.10	3.70±0.20	4.90±0.30	4.90±0.30	MAX6.5
P	2.00±0.05	2.00±0.05	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	8.00±0.10	8.00±0.10
L	8.00±0.20	8.00±0.20	8.00±0.20	8.00±0.20	8.00±0.20	8.00±0.20	12.0±0.20	12.0±0.20	12.0±0.20
T1	0.42±0.03	0.60±0.05	1.00±0.05	1.00±0.05	1.00±0.05	—	—	—	—
T2	—	—	—	—	—	2.00±0.1	2.50±0.1	2.50±0.1	MAX3.2

REEL DIMENSION



Confidential, Do Not Disseminate.



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	13/34
Date:	2021.01.01

10. CAPACITANCE RANGE

NPO

CAP	SIZE	0201							
		10	16	25	50				
0R1~9R0	0.1pF ~ 9pF		L	L	L				
100	10pF		L	L	L				
120	12pF		L	L	L				
150	15pF		L	L	L				
180	18pF		L	L	L				
220	22pF		L	L	L				
270	27pF		L	L	L				
330	33pF		L	L	L				
390	39pF		L	L	L				
470	47pF		L	L	L				
560	56pF		L	L	L				
680	68pF		L	L	L				
820	82pF		L	L	L				
101	100pF		L	L	L				
121	120pF		L	L	L				

NPO

CAP	SIZE	0402				0603				0805			
		10	16	25	50	10	16	25	50	10	16	25	50
0R1	0.1pF	N	N	N	N								
0R2	0.2pF	N	N	N	N								
0R3	0.3pF	N	N	N	N	S	S	S	S				
0R4	0.4pF	N	N	N	N	S	S	S	S				
R47	0.47pF								S				A
0R5~9R0	0.5pF ~ 9.0pF	N	N	N	N	S	S	S	S	A	A	A	A
100	10pF	N	N	N	N	S	S	S	S	A	A	A	A
120	12pF	N	N	N	N	S	S	S	S	A	A	A	A
150	15pF	N	N	N	N	S	S	S	S	A	A	A	A
160	16pF					S	S	S	S				
180	18pF	N	N	N	N	S	S	S	S	A	A	A	A
200	20pF	N	N	N	N	S	S	S	S	A	A	A	A
220	22pF	N	N	N	N	S	S	S	S	A	A	A	A
240	24pF	N	N	N	N	S	S	S	S	A	A	A	A
270	27pF	N	N	N	N	S	S	S	S	A	A	A	A
300	30pF	N	N	N	N	S	S	S	S	A	A	A	A
330	33pF	N	N	N	N	S	S	S	S	A	A	A	A
390	39pF	N	N	N	N	S	S	S	S	A	A	A	A
470	47pF	N	N	N	N	S	S	S	S	A	A	A	A
510	51pF	N	N	N	N	S	S	S	S	A	A	A	A



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	14/34
Date:	2021.01.01

560	56pF	N	N	N	N	S	S	S	S	A	A	A	A
620	62pF	N	N	N	N	S	S	S	S	A	A	A	A
680	68pF	N	N	N	N	S	S	S	S	A	A	A	A
820	82pF	N	N	N	N	S	S	S	S	A	A	A	A
101	100pF	N	N	N	N	S	S	S	S	A	A	A	A
121	120pF	N	N	N	N	S	S	S	S	A	A	A	A
151	150pF	N	N	N	N	S	S	S	S	A	A	A	A
181	180pF	N	N	N	N	S	S	S	S	A	A	A	A
201	200pF	N	N	N	N	S	S	S	S	A	A	A	A
221	220pF	N	N	N	N	S	S	S	S	A	A	A	A
271	270pF	N	N	N	N	S	S	S	S	A	A	A	A
301	300pF	N	N	N	N	S	S	S	S	A	A	A	A
331	330pF	N	N	N	N	S	S	S	S	A	A	A	A
391	390pF	N	N	N	N	S	S	S	S	B	B	B	B
471	470pF	N	N	N	N	S	S	S	S	B	B	B	B
561	560pF	N	N	N	N	S	S	S	S	B	B	B	B
681	680pF	N	N	N	N	S	S	S	S	B	B	B	B
821	820pF	N	N	N	N	S	S	S	S	B	B	B	B
911	910pF	N	N	N	N	S	S	S	S	B	B	B	B
102	1000pF (1 nF / 0.001 uF)	N	N	N	N	S	S	S	S	B	B	B	B
122	1200pF(1.2 nF / 0.0012 uF)					X	X	X	X	B	B	B	B
152	1500pF(1.5 nF / 0.0015 uF)					X	X	X	X	B	B	B	B
182	1800pF(1.8 nF / 0.0018 uF)					X	X	X	X	B	B	B	B
222	2200pF(2.2 nF / 0.0022 uF)					X	X	X	X	B	B	B	B
272	2700pF(2.7 nF / 0.0027 uF)					X	X	X	X	D	D	D	D
332	3300pF(3.3 nF / 0.0033 uF)					X	X	X	X	D	D	D	D
392	3900pF(3.9 nF / 0.0039 uF)					X	X	X	X	D	D	D	D
472	4700pF(4.7 nF / 0.0047 uF)					X	X	X	X	D	D	D	D
562	5600pF(5.6 nF / 0.0056 uF)					X	X	X	X	D	D	D	D
682	6800pF(6.8 nF / 0.0068 uF)					X	X	X	X	D	D	D	D
822	8200pF(8.2 nF / 0.0082 uF)					X	X	X	X	D	D	D	D
103	10000pF (10 nF / 0.01 uF)					X	X	X	X	D	D	D	D
123	12000pF (12 nF / 0.012 uF)									T	T	T	T
153	15000pF (15 nF / 0.015 uF)									T	T	T	T
183	18000pF (18 nF / 0.018 uF)									D	D	D	D
223	22000pF (22 nF / 0.022 uF)									D	D	D	D

NPO

CAP	SIZE	1206				1210				1812		
		10	16	25	50	10	16	25	50	16	25	50
CODE	VDCW											
1R2~8R2	1.2pF ~ 8.2pF	B	B	B	B							
100	10pF	B	B	B	B	C	C	C	C	D	D	D
120	12pF	B	B	B	B	C	C	C	C	D	D	D
150	15pF	B	B	B	B	C	C	C	C	D	D	D
180	18pF	B	B	B	B	C	C	C	C	D	D	D
200	20pF	B	B	B	B	C	C	C	C	D	D	D
220	22pF	B	B	B	B	C	C	C	C	D	D	D



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	15/34
Date:	2021.01.01

240	24pF	B	B	B	B	C	C	C	D	D	D	
270	27pF	B	B	B	B	C	C	C	D	D	D	
300	30pF	B	B	B	B	C	C	C	D	D	D	
330	33pF	B	B	B	B	C	C	C	D	D	D	
390	39pF	B	B	B	B	C	C	C	D	D	D	
470	47pF	B	B	B	B	C	C	C	D	D	D	
510	51pF	B	B	B	B	C	C	C	D	D	D	
560	56pF	B	B	B	B	C	C	C	D	D	D	
620	62pF	B	B	B	B	C	C	C	D	D	D	
680	68pF	B	B	B	B	C	C	C	D	D	D	
820	82pF	B	B	B	B	C	C	C	D	D	D	
101	100pF	B	B	B	B	C	C	C	D	D	D	
121	120pF	B	B	B	B	C	C	C	D	D	D	
151	150pF	B	B	B	B	C	C	C	D	D	D	
181	180pF	B	B	B	B	C	C	C	D	D	D	
221	220pF	B	B	B	B	C	C	C	D	D	D	
271	270pF	B	B	B	B	C	C	C	D	D	D	
301	300pF	B	B	B	B	C	C	C	D	D	D	
331	330pF	B	B	B	B	C	C	C	D	D	D	
391	390pF	B	B	B	B	C	C	C	D	D	D	
471	470pF	B	B	B	B	C	C	C	D	D	D	
561	560pF	B	B	B	B	C	C	C	D	D	D	
681	680pF	B	B	B	B	C	C	C	D	D	D	
821	820pF	B	B	B	B	C	C	C	D	D	D	
911	910pF	B	B	B	B	C	C	C	D	D	D	
102	1000pF (1 nF / 0.001 uF)	B	B	B	B	C	C	C	D	D	D	
122	1200pF(1.2 nF / 0.0012 uF)	B	B	B	B	C	C	C	D	D	D	
152	1500pF(1.5 nF / 0.0015 uF)	B	B	B	B	C	C	C	D	D	D	
182	1800pF(1.8 nF / 0.0018 uF)	B	B	B	B	C	C	C	D	D	D	
222	2200pF(2.2 nF / 0.0022 uF)	B	B	B	B	C	C	C	D	D	D	
272	2700pF(2.7 nF / 0.0027 uF)	B	B	B	B	C	C	C	D	D	D	
332	3300pF(3.3 nF / 0.0033 uF)	B	B	B	B	C	C	C	D	D	D	
392	3900pF(3.9 nF / 0.0039 uF)	B	B	B	B	C	C	C	D	D	D	
472	4700pF(4.7 nF / 0.0047 uF)	B	B	B	B	C	C	C	D	D	D	
562	5600pF(5.6 nF / 0.0056 uF)	B	B	B	B	C	C	C	D	D	D	
682	6800pF(6.8 nF / 0.0068 uF)	C	C	C	C	C	C	C	D	D	D	
822	8200pF(8.2 nF / 0.0082 uF)	D	D	D	D	C	C	C	D	D	D	
103	10000pF (10 nF / 0.01 uF)	D	D	D	D	C	C	C	D	D	D	
123	12000pF (12 nF / 0.012 uF)	P	P	P	P	D	D	D	D	D	D	
153	15000pF (15 nF / 0.015 uF)	P	P	P	P	D	D	D	D	D	D	
183	18000pF (18 nF / 0.018 uF)	P	P	P	P	K	K	K	D	D	D	
223	22000pF (22 nF / 0.022 uF)	P	P	P	P	K	K	K	D	D	D	
273	27000pF (27 nF / 0.027 uF)	P	P	P	P	K	K	K	D	D	D	
333	33000pF (33 nF / 0.033 uF)	P	P	P	P	K	K	K	D	D	D	
393	39000pF (39 nF / 0.039 uF)	P	P	P	P				M	M	M	
473	47000pF (47 nF / 0.047 uF)	J	J	J	J				M	M	M	
563	56000pF (56 nF / 0.056 uF)	J	J	J	J				M	M	M	
683	68000pF (68 nF / 0.068 uF)	G	G	G	G				M	M	M	



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	16/34
Date:	2021.01.01

823	82000pF (82 nF / 0.082 uF)	G	G	G	G				M	M	M	
104	100000pF (100 nF / 0.1 uF)	G	G	G	G				M	M	M	

NPO (Hi-voltage)

CAP	SIZE	0402				0603				0805				1206			
		100	100	200	250	100	200	250	500	630	100	200	250	500	630	1000	2000
0R5~1R2	0.5pF ~ 1.2pF	N	S	S	S	A	A	A	A	A							
1R5~8R2	1.5pF ~ 8.2pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
100	10pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
120	12pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
150	15pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
180	18pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
200	20pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
220	22pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
240	24pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
270	27pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
300	30pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	B
330	33pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	C
390	39pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	B	C
470	47pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	C	C
560	56pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	C	D
680	68pF	N	S	S	S	A	A	A	A	A	B	B	B	B	B	C	D
820	82pF	N	S	S	S	A	A	A	B	B	B	B	B	B	B	D	D
101	100pF	N	S	S	S	A	A	B	B	B	B	B	B	B	B	D	D
121	120pF	N	S	S	S	A	A	B	D	D	B	B	B	B	B	D	G
151	150pF	N	S	S	S	A	B	D	D	D	B	B	B	B	B	D	G
181	180pF	N	S	S	S	A	B	D	D	D	B	B	B	B	B	G	G
221	220pF	N	S	S	S	A	D	D	D	D	B	B	B	B	B	G	G
271	270pF		S	X	X	A	D	D	D	D	B	B	C	C	C	G	P
331	330pF		S	X	X	A	D	D	D	D	B	B	C	C	C	G	P
391	390pF		S	X	X	B	D	D	D	D	B	B	C	C	C	G	P
471	470pF		S	X	X	B	D	D	D	I	I	B	C	C	C	G	
561	560pF		S			B	D	D	I	I	B	C	D	D	D	G	
681	680pF		S			B	D	D	I	I	B	C	D	D	D	G	
821	820pF		S			B	D	D	I	I	B	C	G	G	G	G	
102	1000pF (1 nF / 0.001 uF)		S			B	D	D	I	I	B	C	G	G	G	G	
122	1200pF(1.2 nF / 0.0012 uF)		X			B	D	D			B	C	G	G	G		
152	1500pF(1.5 nF / 0.0015 uF)		X			B	D	D			B	D	G	G	G		
182	1800pF(1.8 nF / 0.0018 uF)					B	D	D			B	D	G	G	G		
222	2200pF(2.2 nF / 0.0022 uF)					B	D	D			B	D	G	G	G		
272	2700pF(2.7 nF / 0.0027 uF)					D					B	D	G				
332	3300pF(3.3 nF / 0.0033 uF)					D					B	D	G				
392	3900pF(3.9 nF / 0.0039 uF)					D					B	D	G				
472	4700pF(4.7 nF / 0.0047 uF)					D					B	D	G				
562	5600pF(5.6 nF / 0.0056 uF)					D					B						
682	6800pF(6.8 nF / 0.0068 uF)					D					C						
822	8200pF(8.2 nF / 0.0082 uF)										D						



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	17/34
Date:	2021.01.01

103	10000pF (10 nF / 0.01 uF)								D							
123	12000pF (12 nF / 0.012 uF)								P							
153	15000pF (15 nF / 0.015 uF)								P							
183	18000pF (18 nF / 0.018 uF)								P							
223	22000pF (22 nF / 0.022 uF)								P							

NPO (High-voltage)

CAP	SIZE	1210							1808			1812						
		100	200	250	500	630	1000	2000	1000	2000	3000	100	200	250	500	630	1000	2000
2R0~2R7	2.0pF ~ 2.7pF								D	D	D							
3R3~8R2	3.3pF ~ 8.2pF								D	D	D							
100	10pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
120	12pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
150	15pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
180	18pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
200	20pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
220	22pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
240	24pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
270	27pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
300	30pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
330	33pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
390	39pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
470	47pF	C	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D
510	51pF	C	C	C	C	C			D	D	D	D	D	D	D	D	D	D
560	56pF	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D	D
680	68pF	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D	D
820	82pF	C	C	C	C	C	C	D	D	D	D	D	D	D	D	D	D	D
101	100pF	C	C	C	C	C	D	D	D	K	K	D	D	D	D	D	D	D
121	120pF	C	C	C	C	C	D	D	D	K	K	D	D	D	D	D	D	D
151	150pF	C	C	C	C	C	D	G	D	K	K	D	D	D	D	D	D	D
181	180pF	C	C	C	C	C	D	G	D	K	K	D	D	D	D	D	K	K
221	220pF	C	C	C	C	C	G	G	D	K	K	D	D	D	D	D	D	K
271	270pF	C	C	C	C	C	G	K	K	K	K	D	D	D	D	D	D	K
331	330pF	C	C	C	C	C	G	K	K	K	K	D	D	D	D	D	K	K
391	390pF	C	C	C	C	C	G	M	K	K		D	D	D	D	D	K	K
471	470pF	C	C	C	C	C	G	M	K	K		D	D	D	D	D	K	K
561	560pF	C	C	C	C	C	G		K	K		D	D	D	D	D	K	
681	680pF	C	C	C	C	C	G		K	K		D	D	D	D	D	K	
821	820pF	C	C	C	C	C	G		K			D	D	D	D	D	K	
102	1000pF (1 nF / 0.001 uF)	C	D	D	D	D	G		K			D	D	D	D	D	K	K
122	1200pF(1.2 nF / 0.0012 uF)	C	D	D	D	D						D	D	D	D	D	D	K
152	1500pF(1.5 nF / 0.0015 uF)	C	D	D	D	D						D	D	D	D	D	D	K
182	1800pF(1.8 nF / 0.0018 uF)	C	D	D	D	D						D	D	D	D	D	D	
222	2200pF(2.2 nF / 0.0022 uF)	C	D	D	D	D						D	D	D	D	D	D	
272	2700pF(2.7 nF / 0.0027 uF)	C	D	D	D	D						D	D	D	D	D	D	
332	3300pF(3.3 nF / 0.0033 uF)	C	D	D	D	D						D	D	D	D	D	D	
392	3900pF(3.9 nF / 0.0039 uF)	C	D	D	D	D						D	D	D	D	D	D	
472	4700pF(4.7 nF / 0.0047 uF)	C	G	G								D	D	D	D	D	D	
562	5600pF(5.6 nF / 0.0056 uF)	C	G	G								D	D	D	D	D	D	

Confidential, Do Not Disseminate.



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02-A-#H022
Version:	A
Page:	18/34
Date:	2021.01.01

682	6800pF(6.8 nF / 0.0068 uF)	C	G	G						D	D	D					
822	8200pF(8.2 nF / 0.0082 uF)	C	G	G						D							
103	10000pF (10 nF / 0.01 uF)	C	G	G						D							
123	12000pF (12 nF / 0.012 uF)	D								D							
153	15000pF (15 nF / 0.015 uF)	D								D							
183	18000pF (18 nF / 0.018 uF)	K								D							
223	22000pF (22 nF / 0.022 uF)	K								D							
273	27000pF (27 nF / 0.027 uF)	K								D							
333	33000pF (33 nF / 0.033 uF)	K								D							
393	39000pF (39 nF / 0.039 uF)									M							
473	47000pF (47 nF / 0.047 uF)									M							
563	56000pF (56 nF / 0.056 uF)									M							
683	68000pF (68 nF / 0.068 uF)									M							
823	82000pF (82 nF / 0.082 uF)									M							
104	100000pF (100 nF / 0.1 uF)									M							



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	19/34
Date:	2021.01.01

X7R

CAP	SIZE	0201						
		10	16	25	50			
101	100pF		L	L	L			
121	120pF		L	L	L			
151	150pF		L	L	L			
181	180pF		L	L	L			
221	220pF		L	L	L			
271	270pF		L	L	L			
331	330pF		L	L	L			
391	390pF		L	L	L			
471	470pF		L	L	L			
561	560pF		L	L	L			
681	680pF		L	L	L			
821	821pF		L	L	L			
102	1000pF (1 nF / 0.001 uF)	L	L	L	L			
122	1200pF(1.2 nF / 0.0012 uF)	L	L	L				
152	1500pF(1.5 nF / 0.0015 uF)	L	L	L				
182	1800pF(1.8 nF / 0.0018 uF)	L	L					
222	2200pF(2.2 nF / 0.0022 uF)	L	L					
272	2700pF(2.7 nF / 0.0027 uF)	L	L					
332	3300pF(3.3 nF / 0.0033 uF)	L	L					
392	3900pF(3.9 nF / 0.0039 uF)	L	L					
472	4700pF(4.7 nF / 0.0047 uF)	L	L					
562	5600pF(5.6 nF / 0.0056 uF)	L						
682	6800pF(6.8 nF / 0.0068 uF)	L						
822	8200pF(8.2 nF / 0.0082 uF)	L						
103	10 nF (0.01 uF)	L	L					



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	20/34
Date:	2021.01.01

X7R

CAP	SIZE	0402				0603				0805			
		10	16	25	50	10	16	25	50	10	16	25	50
CODE	VDCW												
101	100pF	N	N	N	N	S	S	S	S	B	B	B	B
121	120pF	N	N	N	N	S	S	S	S	B	B	B	B
151	150pF	N	N	N	N	S	S	S	S	B	B	B	B
181	180pF	N	N	N	N	S	S	S	S	B	B	B	B
221	220pF	N	N	N	N	S	S	S	S	B	B	B	B
271	270pF	N	N	N	N	S	S	S	S	B	B	B	B
331	330pF	N	N	N	N	S	S	S	S	B	B	B	B
391	390pF	N	N	N	N	S	S	S	S	B	B	B	B
471	470pF	N	N	N	N	S	S	S	S	B	B	B	B
561	560pF	N	N	N	N	S	S	S	S	B	B	B	B
681	680pF	N	N	N	N	S	S	S	S	B	B	B	B
821	821pF	N	N	N	N	S	S	S	S	B	B	B	B
102	1000pF (1 nF / 0.001 uF)	N	N	N	N	S	S	S	S	B	B	B	B
122	1200pF(1.2 nF / 0.0012 uF)	N	N	N	N	S	S	S	S	B	B	B	B
152	1500pF(1.5 nF / 0.0015 uF)	N	N	N	N	S	S	S	S	B	B	B	B
182	1800pF(1.8 nF / 0.0018 uF)	N	N	N	N	S	S	S	S	B	B	B	B
222	2200pF(2.2 nF / 0.0022 uF)	N	N	N	N	S	S	S	S	B	B	B	B
272	2700pF(2.7 nF / 0.0027 uF)	N	N	N	N	S	S	S	S	B	B	B	B
332	3300pF(3.3 nF / 0.0033 uF)	N	N	N	N	S	S	S	S	B	B	B	B
392	3900pF(3.9 nF / 0.0039 uF)	N	N	N	N	S	S	S	S	B	B	B	B
472	4700pF(4.7 nF / 0.0047 uF)	N	N	N	N	S	S	S	S	B	B	B	B
562	5600pF(5.6 nF / 0.0056 uF)	N	N	N	N	S	S	S	S	B	B	B	B
682	6800pF(6.8 nF / 0.0068 uF)	N	N	N	N	S	S	S	S	B	B	B	B
822	8200pF(8.2 nF / 0.0082 uF)	N	N	N	N	S	S	S	S	B	B	B	B
103	10 nF (0.01 uF)	N	N	N	N	S	S	S	S	B	B	B	B
123	12 nF (0.012 uF)	N	N	N		S	S	S	S	B	B	B	B
153	15 nF (0.015 uF)	N	N	N		S	S	S	S	B	B	B	B
183	18 nF (0.018 uF)	N	N	N		S	S	S	S	B	B	B	B
223	22 nF (0.022 uF)	N	N	N	N	S	S	S	S	B	B	B	B
273	27 nF (0.027 uF)	N	N	N		S	S	S	S	B	B	B	B
333	33 nF (0.033 uF)	N	N	N	N	S	S	S	X	B	B	B	B
393	39 nF (0.039 uF)	N	N	N		S	S	S	X	B	B	B	B
473	47 nF (0.047 uF)	N	N	N	N	S	S	S	X	B	B	B	B
563	56 nF (0.056 uF)	N	N			S	S	S	X	B	B	B	B
683	68 nF (0.068 uF)	N	N		N	S	S	S	X	B	B	B	B
823	82 nF (0.082 uF)	N	N			S	S	S	X	B	B	B	B
104	100 nF (0.1 uF)	N	N	N	N	S	S	S	X	B	B	B	B
124	120 nF (0.12 uF)					S	S	X		B	B	B	D
154	150 nF (0.15 uF)					S	S	X		D	D	D	D
184	180 nF (0.18 uF)					S	S	X		D	D	D	D
224	220 nF (0.22 uF)	N	N	N		S	S	X	X	D	D	D	D
274	270 nF (0.27 uF)					X	X	X		D	D	D	I
334	330 nF (0.33 uF)					X	X	X		D	D	D	I
394	390 nF (0.39 uF)					X	X	X		D	D	D	I
474	470 nF (0.47 uF)	N				X	X	X	X	D	D	D	I

**SYNTON-TECH CORPORATION****CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02-A-#H022
Version:	A
Page:	21/34
Date:	2021.01.01

564	560 nF (0.56 uF)				X	X			D	D	D	
684	680 nF (0.68 uF)				X	X			D	D	D	
824	820 nF (0.82 uF)				X	X			D	D	D	
105	1.0 uF				X	X	X	X	D	D	D	I
155	1.5uF								I	I	I	
225	2.2 uF				X	X			I	I	I	I
335	3.3 uF											
475	4.7 uF								I	I	I	
685	6.8 uF											
106	10 uF								I	I		



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	22/34
Date:	2021.01.01

X7R

CAP	SIZE	1206					1210				1812			
		6.3	10	16	25	50	10	16	25	50	10	16	25	50
151	150pF		B	B	B	B								
181	180pF		B	B	B	B								
221	220pF		B	B	B	B								
271	270pF		B	B	B	B								
331	330pF		B	B	B	B								
391	390pF		B	B	B	B								
471	470pF		B	B	B	B								
561	560pF		B	B	B	B								
681	680pF		B	B	B	B								
821	821pF		B	B	B	B								
102	1000pF (1 nF / 0.001 uF)		B	B	B	B	C	C	C	C	D	D	D	D
122	1200pF(1.2 nF / 0.0012 uF)		B	B	B	B	C	C	C	C	D	D	D	D
152	1500pF(1.5 nF / 0.0015 uF)		B	B	B	B	C	C	C	C	D	D	D	D
182	1800pF(1.8 nF / 0.0018 uF)		B	B	B	B	C	C	C	C	D	D	D	D
222	2200pF(2.2 nF / 0.0022 uF)		B	B	B	B	C	C	C	C	D	D	D	D
272	2700pF(2.7 nF / 0.0027 uF)		B	B	B	B	C	C	C	C	D	D	D	D
332	3300pF(3.3 nF / 0.0033 uF)		B	B	B	B	C	C	C	C	D	D	D	D
392	3900pF(3.9 nF / 0.0039 uF)		B	B	B	B	C	C	C	C	D	D	D	D
472	4700pF(4.7 nF / 0.0047 uF)		B	B	B	B	C	C	C	C	D	D	D	D
562	5600pF(5.6 nF / 0.0056 uF)		B	B	B	B	C	C	C	C	D	D	D	D
682	6800pF(6.8 nF / 0.0068 uF)		B	B	B	B	C	C	C	C	D	D	D	D
822	8200pF(8.2 nF / 0.0082 uF)		B	B	B	B	C	C	C	C	D	D	D	D
103	10 nF (0.01 uF)		B	B	B	B	C	C	C	C	D	D	D	D
123	12 nF (0.012 uF)		B	B	B	B	C	C	C	C	D	D	D	D
153	15 nF (0.015 uF)		B	B	B	B	C	C	C	C	D	D	D	D
183	18 nF (0.018 uF)		B	B	B	B	C	C	C	C	D	D	D	D
223	22 nF (0.022 uF)		B	B	B	B	C	C	C	C	D	D	D	D
273	27 nF (0.027 uF)		B	B	B	B	C	C	C	C	D	D	D	D
333	33 nF (0.033 uF)		B	B	B	B	C	C	C	C	D	D	D	D
393	39 nF (0.039 uF)		B	B	B	B	C	C	C	C	D	D	D	D
473	47 nF (0.047 uF)		B	B	B	B	C	C	C	C	D	D	D	D
563	56 nF (0.056 uF)		B	B	B	B	C	C	C	C	D	D	D	D
683	68 nF (0.068 uF)		B	B	B	B	C	C	C	C	D	D	D	D
823	82 nF (0.082 uF)		B	B	B	B	C	C	C	C	D	D	D	D
104	100 nF (0.1 uF)		B	B	B	B	C	C	C	C	D	D	D	D
124	120 nF (0.12 uF)		B	B	B	B	C	C	C	C	D	D	D	D
154	150 nF (0.15 uF)		C	C	C	C	C	C	C	C	D	D	D	D
184	180 nF (0.18 uF)		C	C	C	C	C	C	C	C	D	D	D	D
224	220 nF (0.22 uF)		C	C	C	C	C	C	C	C	D	D	D	D
274	270 nF (0.27 uF)		C	C	C	D	C	C	C	C	D	D	D	D
334	330 nF (0.33 uF)		C	C	C	D	C	C	C	D	D	D	D	D
394	390 nF (0.39 uF)		C	C	J	P	C	C	C	D	D	D	D	D
474	470 nF (0.47 uF)		J	J	J	P	C	C	C	D	D	D	D	D
564	560 nF (0.56 uF)		J	J	J	P	D	D	D	D	D	D	D	D
684	680 nF (0.68 uF)		J	J	J	P	D	D	D	D	D	D	D	K

**SYNTON-TECH CORPORATION****CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02-A-#H022
Version:	A
Page:	23/34
Date:	2021.01.01

824	820 nF (0.82 uF)		J	J	J	P	D	D	D	D	D	D	D	K
105	1.0 uF		J	J	J	P	D	D	D	D	D	D	D	K
155	1.5 uF	J	J	J	P			K	G	M				
225	2.2 uF	J	J	J	P	P		K	G	M				M
335	3.3 uF		P	P	P			K	G					
475	4.7 uF	P	P	P	P	P	K	K	K	M				
685	6.8 uF													
106	10 uF	P	P	P	P		K	K	K	M				
226	22 uF	P	P	P			M	M	M					
476	47 uF						M							



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	24/34
Date:	2021.01.01

X7R (Hi-voltage)

CAP	SIZE	0603						0805						1206					
		100	100	200	250	500	630	100	200	250	500	630	1000	2000					
CODE	VDCW	100	100	200	250	500	630	100	200	250	500	630	1000	2000					
101	100pF	S	B	B	B	B	B		D	D	D	D	D	D					
121	120pF	S	B	B	B	B	B		D	D	D	D	D	D					
151	150pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
181	180pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
221	220pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
271	270pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
331	330pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
391	390pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
471	470pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
561	560pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
681	680pF	S	B	B	B	B	B	B	D	D	D	D	D	D					
821	821pF	S	B	B	B	B	B	B	D	D	D	D	D	G					
102	1000pF (1 nF / 0.001 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
122	1200pF(1.2 nF / 0.0012 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
152	1500pF(1.5 nF / 0.0015 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
182	1800pF(1.8 nF / 0.0018 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
222	2200pF(2.2 nF / 0.0022 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
272	2700pF(2.7 nF / 0.0027 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
332	3300pF(3.3 nF / 0.0033 uF)	S	B	B	B	B	B	B	D	D	D	D	D	G					
392	3900pF(3.9 nF / 0.0039 uF)	S	B	B	B	B	B	B	D	D	D	D	D						
472	4700pF(4.7 nF / 0.0047 uF)	S	B	B	B	D	D	B	D	D	D	D	D						
562	5600pF(5.6 nF / 0.0056 uF)	S	B	D	D	D	D	B	D	D	D	D	D						
682	6800pF(6.8 nF / 0.0068 uF)	S	B	D	D	D	D	B	D	D	D	D	D						
822	8200pF(8.2 nF / 0.0082 uF)	S	B	D	D	D	D	B	D	D	D	D	D						
103	10 nF (0.01 uF)	S	B	D	D	D	D	B	D	D	D	D	D						
123	12 nF (0.012 uF)	X	B	D	D	D	D	B	D	D	D	D	G						
153	15 nF (0.015 uF)	X	B	D	D	D	D	B	D	D	D	D	G						
183	18 nF (0.018 uF)	X	B	D	D	D	D	B	D	D	D	D	D						
223	22 nF (0.022 uF)	X	B	D	D	D	D	B	D	D	D	G	G						
273	27 nF (0.027 uF)	X	D	D	D			B	D	D	G	G							
333	33 nF (0.033 uF)	X	D	D	D			B	G	G	G	G							
393	39 nF (0.039 uF)	X	D	D	D			B	G	G	G	G							
473	47 nF (0.047 uF)	X	D	D	D			B	G	G	G	G							
563	56 nF (0.056 uF)	X	D	D	D			B	G	G	G	G							
683	68 nF (0.068 uF)	X	D	D	D			B	G	G									
823	82 nF (0.082 uF)	X	D	D				D	G	G									
104	100 nF (0.1 uF)	X	D	D				D	G	G									
124	120 nF (0.12 uF)							D											
154	150 nF (0.15 uF)							G											
184	180 nF (0.18 uF)							G											
224	220 nF (0.22 uF)		T					G											
274	270 nF (0.27 uF)							G											
334	330 nF (0.33 uF)							G											
394	390 nF (0.39 uF)							G											
474	470 nF (0.47 uF)		I					G											



SYNTON-TECH CORPORATION

**CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02-A-#H022
Version:	A
Page:	25/34
Date:	2021.01.01

564	560 nF (0.56 uF)					P					
684	680 nF (0.68 uF)					P					
824	820 nF (0.82 uF)					P					
105	1uF					P					
225	2.2uF					P					



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	26/34
Date:	2021.01.01

X7R (Hi-voltage)

CAP	SIZE	1210						1808			1812							
		100	200	250	500	630	1000	1000	2000	3000	100	200	250	500	630	1000	2000	3000
101	100pF		D	D	D	D	D											
121	120pF		D	D	D	D	D											
151	150pF		D	D	D	D	D	D	D	D								
181	180pF		D	D	D	D	D	D	D	D								
221	220pF		D	D	D	D	D	D	D	D								
271	270pF		D	D	D	D	D	D	D	D						D	D	K
331	330pF		D	D	D	D	D	D	D	K						D	D	K
391	390pF		D	D	D	D	D	D	D	K						D	D	K
471	470pF		D	D	D	D	D	D	D	K						D	D	K
561	560pF		D	D	D	D	D	D	D	K						D	D	K
681	680pF		C	C	D	D	D	D	D	K						D	D	K
821	821pF		C	C	D	D	D	D	D	K						D	D	K
102	1000pF (1 nF / 0.001 uF)	C	C	C	D	D	D	K	K	D	D	D	D	D	D	D	D	K
122	1200pF(1.2 nF / 0.0012 uF)	C	C	C	D	D	D	K	K	D	D	D	D	D	D	D	D	K
152	1500pF(1.5 nF / 0.0015 uF)	C	C	C	D	D	D	K	K	D	D	D	D	D	D	D	D	K
182	1800pF(1.8 nF / 0.0018 uF)	C	C	C	D	D	D	K	K	D	D	D	D	D	D	G	M	
222	2200pF(2.2 nF / 0.0022 uF)	C	C	C	D	D	D	K		D	D	D	D	D	D	G	M	
272	2700pF(2.7 nF / 0.0027 uF)	C	C	C	D	D	D	K		D	D	D	D	D	D	G	M	
332	3300pF(3.3 nF / 0.0033 uF)	C	C	C	D	D	D	K		D	D	D	D	D	D	K	M	
392	3900pF(3.9 nF / 0.0039 uF)	C	C	C	D	D	G	D	K		D	D	D	D	D	D	K	
472	4700pF(4.7 nF / 0.0047 uF)	C	C	C	D	D	G	D	K		D	D	D	D	D	D	K	
562	5600pF(5.6 nF / 0.0056 uF)	C	C	C	D	D	G	K	K		D	D	D	D	D	D	M	
682	6800pF(6.8 nF / 0.0068 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	M	
822	8200pF(8.2 nF / 0.0082 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	M	
103	10 nF (0.01 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	M	
123	12 nF (0.012 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	K	
153	15 nF (0.015 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	K	
183	18 nF (0.018 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	M	
223	22 nF (0.022 uF)	C	C	C	D	D	G	K			D	D	D	D	D	D	M	
273	27 nF (0.027 uF)	C	C	C	G	G					D	D	D	D	D	D		
333	33 nF (0.033 uF)	C	C	C	G	G		K			D	D	D	D	D	M		
393	39 nF (0.039 uF)	C	C	C	G	G					D	D	D	D	D	D		
473	47 nF (0.047 uF)	C	D	D	G	G		K			D	D	D	D	D	D	M	
563	56 nF (0.056 uF)	C	D	D	G	G					D	D	D	K	K			
683	68 nF (0.068 uF)	C	G	G	K	K					D	D	D	K	K			
823	82 nF (0.082 uF)	C	G	G	K	K					D	D	D	K	K			
104	100 nF (0.1 uF)	C	G	G	K	K					D	D	D	K	K	M		
124	120 nF (0.12 uF)	C	G	G							D	D	D	M	M			
154	150 nF (0.15 uF)	D	M	M							D	K	K	M	M			
184	180 nF (0.18 uF)	D	M	M							D	K	K	M	M			
224	220 nF (0.22 uF)	D	M	M							D	K	K	M	M			
274	270 nF (0.27 uF)	G	M	M							D	K	K					
334	330 nF (0.33 uF)	G	M	M							D	K	K					
394	390 nF (0.39 uF)	M	M	M							D	K	K					
474	470 nF (0.47 uF)	M	M	M							K	K	K					



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02-A-#H022
Version:	A
Page:	27/34
Date:	2021.01.01

564	560 nF (0.56 uF)	M							K	M	M					
684	680 nF (0.68 uF)	K							K	M	M					
824	820 nF (0.82 uF)	K							K	M	M					
105	1.0uF	K							K	M	M					
155	1.5uF	M							K							
225	2.2uF	M							M							



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	28/34
Date:	2021.01.01

X7R (Hi-voltage)

CAP	SIZE	2220						
		1000	2000	3000				
101	100pF							
151	150pF							
181	180pF							
221	220pF							
271	270pF							
331	330pF							
391	390pF							
471	470pF							
561	560pF							
681	680pF							
821	821pF							
102	1000pF (1 nF / 0.001 uF)	V	V	V				
122	1200pF(1.2 nF / 0.0012 uF)	V	V	V				
152	1500pF(1.5 nF / 0.0015 uF)	V	V	V				
182	1800pF(1.8 nF / 0.0018 uF)	V	V	V				
222	2200pF(2.2 nF / 0.0022 uF)	V	V	V				
272	2700pF(2.7 nF / 0.0027 uF)	V	V	V				
332	3300pF(3.3 nF / 0.0033 uF)	V	V	V				
392	3900pF(3.9 nF / 0.0039 uF)	V	V	V				
472	4700pF(4.7 nF / 0.0047 uF)	V	V					
562	5600pF(5.6 nF / 0.0056 uF)	V	V					
682	6800pF(6.8 nF / 0.0068 uF)	V	V					
822	8200pF(8.2 nF / 0.0082 uF)	V	V					
103	10 nF (0.01 uF)	V	V					
123	12 nF (0.012 uF)	V						
153	15 nF (0.015 uF)	V						
183	18 nF (0.018 uF)	V						
223	22 nF (0.022 uF)	V						
273	27 nF (0.027 uF)	V						
333	33 nF (0.033 uF)	V						
393	39 nF (0.039 uF)	V						
473	47 nF (0.047 uF)	V						
563	56 nF (0.056 uF)							
683	68 nF (0.068 uF)							
823	82 nF (0.082 uF)							
104	100 nF (0.1 uF)							
124	120 nF (0.12 uF)							
154	150 nF (0.15 uF)							
184	180 nF (0.18 uF)							
224	220 nF (0.22 uF)							



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	29/34
Date:	2021.01.01

274	270 nF (0.27 uF)												
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X5R

CAP	SIZE	0201											
		6.3	10	16	25	50							
101	100pF			L	L	L							
121	120pF			L	L	L							
151	150pF			L	L	L							
181	180pF			L	L	L							
221	220pF			L	L	L							
271	270pF			L	L	L							
331	330pF			L	L	L							
391	390pF			L	L	L							
471	470pF			L	L	L							
561	560pF			L	L	L							
681	680pF			L	L	L							
821	821pF			L	L	L							
102	1000pF (1 nF / 0.001 uF)		L	L	L	L							
152	1500pF(1.5 nF / 0.0015 uF)		L	L									
222	2200pF(2.2 nF / 0.0022 uF)		L	L									
272	2700pF(2.7 nF / 0.0027 uF)		L	L									
332	3300pF(3.3 nF / 0.0033 uF)		L	L									
472	4700pF(4.7 nF / 0.0047 uF)		L	L									
682	6800pF(6.8 nF / 0.0068 uF)		L										
103	10 nF (0.01 uF)	L	L	L	L								
153	15 nF (0.015 uF)	L	L										
223	22 nF (0.022 uF)	L	L										
273	27 nF (0.027 uF)	L	L										
333	33 nF (0.033 uF)	L	L										
393	39 nF (0.039 uF)	L	L										
473	47 nF (0.047 uF)	L	L										
563	56 nF (0.056 uF)	L	L										
683	68 nF (0.068 uF)	L	L										
823	82 nF (0.082 uF)	L	L										
104	100 nF (0.1 uF)	L	L	L	L								
224	220 nF (0.22 uF)	L	L										
474	470 nF (0.47 uF)	L											
105	1 uF	L	L										
225	10 uF	L											



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	30/34
Date:	2021.01.01

X5R

CAP	SIZE	0402					0603					0805				
		6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
273	27 nF (0.027 uF)			N												
333	33 nF (0.033 uF)			N												
393	39 nF (0.039 uF)			N												
473	47 nF (0.047 uF)			N												
563	56 nF (0.056 uF)		N	N												
683	68 nF (0.068 uF)		N	N												
823	82 nF (0.082 uF)	N	N	N												
104	100 nF (0.1 uF)	N	N	N	N	N										
154	150 nF (0.15 uF)	N	N	N	N											
224	220 nF (0.22 uF)	N	N	N	N	N			X	X						
274	270 nF (0.27 uF)							X	X	X						
334	330 nF (0.33 uF)	N	N				X	X	X	X						
394	390 nF (0.39 uF)						X	X	X	X						
474	470 nF (0.47 uF)	N	N	E	E	E	X	X	X	X	X					
684	680 nF (0.68 uF)	N	N				X	X	X	X						
824	820 nF (0.82 uF)						X	X	X							
105	1.0uF	N	N	N	N		X	X	X	X	X		D	D	D	I
155	1.5uF						X						I	I	I	I
225	2.2uF	N	N	E	E		X	X	X	X	X	I	I	I	I	I
335	3.3uF						X	X				I	I	I	I	
475	4.7uF	E	E	E			X	X	X	X		I	I	I	I	I
685	6.8uF															
106	10 uF	E	E				X	X	X	X		I	I	I	I	I
226	22 uF						X	X				I	I	I	I	
476	47 uF						X					I	I			
107	100 uF															



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	31/34
Date:	2021.01.01

X5R

CAP	SIZE	1206					1210					1812
		6.3	10	16	25	50	6.3	10	16	25	50	
273	27 nF (0.027 uF)											
333	33 nF (0.033 uF)											
393	39 nF (0.039 uF)											
473	47 nF (0.047 uF)											
563	56 nF (0.056 uF)											
683	68 nF (0.068 uF)											
823	82 nF (0.082 uF)											
104	100 nF (0.1 uF)											
154	150 nF (0.15 uF)											
224	220 nF (0.22 uF)											
274	270 nF (0.27 uF)											
334	330 nF (0.33 uF)											
394	390 nF (0.39 uF)											
474	470 nF (0.47 uF)											
684	680 nF (0.68 uF)											
824	820 nF (0.82 uF)											
105	1.0uF											
155	1.5uF		J	J				K	K			
225	2.2uF		J	J	P	P		K	K			
335	3.3uF		P	P	P							
475	4.7uF	P	P	P	P	P		K	K	K		
685	6.8uF	P	P									
106	10 uF	P	P	P	P	P	K	K	K	K	M	
226	22 uF	P	P	P	P		M	M	M	M		
476	47 uF	P	P				M	M	M			
107	100 uF	P					M	M				U



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	32/34
Date:	2021.01.01

Y5V

CAP	SIZE	0402					0603					0805				
		6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
103	10 nF (0.01 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
123	12 nF (0.012 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
153	15 nF (0.015 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
183	18 nF (0.018 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
223	22 nF (0.022 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
273	27 nF (0.027 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
333	33 nF (0.033 uF)	N	N	N	N		S	S	S	S		A	A	A	A	A
393	39 nF (0.039 uF)	N	N	N			S	S	S	S		A	A	A	A	A
473	47 nF (0.047 uF)	N	N	N			S	S	S	S		A	A	A	A	A
563	56 nF (0.056 uF)	N	N	N			S	S	S	S		A	A	A	A	A
683	68 nF (0.068 uF)	N	N	N			S	S	S	S		A	A	A	A	A
823	82 nF (0.082 uF)	N	N	N			S	S	S	S		A	A	A	A	A
104	100 nF (0.1 uF)	N	N	N			S	S	S	S		A	A	A	A	A
124	120 nF (0.12 uF)	N					S	S	S	S		A	A	A	A	A
154	150 nF (0.15 uF)	N	N				S	S	S	S		A	A	A	A	A
224	220 nF (0.22 uF)	N	N	N			S	S	S	S		A	A	A	A	A
334	330 nF (0.33 uF)	N	N	N			S	S	S	X		B	B	B	B	B
474	470 nF (0.47 uF)	N	N	N			S	S	X	X		B	B	B	B	B
684	680 nF (0.68 uF)	N					S	X	X			B	B	D	D	D
105	1 uF	N	N				S	X	X			B	B	D	D	D
155	1.5 uF						S					D	D			
225	2.2 uF						S	S	X			D	D	I		
335	3.3 uF											D	D			
475	4.7 uF						X	X				D	D	I		
685	6.8 uF											I				
106	10 uF											I	I	I		
226	22 uF											I	I			



SYNTON-TECH CORPORATION
CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)

File No.:	CC-02—A-#H022
Version:	A
Page:	33/34
Date:	2021.01.01

Y5V

CAP	SIZE	1206					1210					1812					
		6.3	10	16	25	35	50	6.3	10	16	25	35	50	10	16	25	50
103	10 nF (0.01 uF)		B	B	B		B										
123	12 nF (0.012 uF)		B	B	B		B										
153	15 nF (0.015 uF)		B	B	B		B										
183	18 nF (0.018 uF)		B	B	B		B										
223	22 nF (0.022 uF)		B	B	B		B										
273	27 nF (0.027 uF)		B	B	B		B										
333	33 nF (0.033 uF)		B	B	B		B										
393	39 nF (0.039 uF)		B	B	B		B										
473	47 nF (0.047 uF)		B	B	B		B										
563	56 nF (0.056 uF)		B	B	B		B										
683	68 nF (0.068 uF)		B	B	B		B										
823	82 nF (0.082 uF)		B	B	B		B										
104	100 nF (0.1 uF)		B	B	B		B		C	C	C		C	D	D	D	D
124	120 nF (0.12 uF)		B	B	B		B		C	C	C		C	D	D	D	D
154	150 nF (0.15 uF)		B	B	B		B		C	C	C		C	D	D	D	D
224	220 nF (0.22 uF)		B	B	B		B		C	C	C		C	D	D	D	D
334	330 nF (0.33 uF)		B	B	B		B		C	C	C		C	D	D	D	D
474	470 nF (0.47 uF)		B	B	B		B		C	C	C		C	D	D	D	D
684	680 nF (0.68 uF)		B	B	B		B		C	C	C		C	D	D	D	D
105	1 uF		C	C	C		C		C	C	C		C	D	D	D	D
155	1.5 uF		C	C	C				C	C	C		D	D	D	D	D
225	2.2 uF		C	C	C		J		C	C	C		G	D	D	D	D
335	3.3 uF		J	J	J				C	C	C		D	D	D	D	D
475	4.7 uF		J	J	J	J	P		C	C	D		G	D	D	D	D
685	6.8 uF		J	J					C	C	D		K	D	D	D	D
106	10 uF		J	J	P				D	D	G	K	K	D	D	D	K
226	22 uF		P	P					K	K							
476	47uF	P						K	K				M				
107	100uF						M										



SYNTON-TECH CORPORATION

**CHIP MULTILAYER CERAMIC
CAPACITOR (AEC-Q200)**

File No.:	CC-02—A-#H022
Version:	A
Page:	34/34
Date:	2021.01.01

Y5V (Hi-voltage)

CAP	SIZE	0805			1206			1210			1812		
		100	200	250	100	200	250	100	200	250	100	200	250
103	10 nF (0.01 uF)	B	B	B	B	B	B	C	C	C	D	D	D
153	15 nF (0.015 uF)	B	B	B	B	B	B	C	C	C	D	D	D
223	22 nF (0.022 uF)	B	B	B	B	B	B	C	C	C	D	D	D
333	33 nF (0.033 uF)	B	B	B	B	B	B	C	C	C	D	D	D
473	47 nF (0.047 uF)	B	B	B	B	B	B	C	C	C	D	D	D
683	68 nF (0.068 uF)	B	B	B	B	B	B	C	C	C	D	D	D
104	100 nF (0.1 uF)	B			B	B	B	C	C	C	D	D	D
154	150 nF (0.15 uF)				C	C	C	C	C	C	D	D	D
224	220 nF (0.22 uF)				C			C			D	D	D
334	330 nF (0.33 uF)							C			D	D	D
474	470 nF (0.47 uF)										D	D	D
684	680 nF (0.68 uF)										D	D	D
105	1 uF										D		

● Chip Thickness :

N = **0.50 ± 0.05**
 S = **0.80 ± 0.07**
 X = **0.80 + 0.15/-0.10**
 A = **0.60 ± 0.10**
 B = **0.80 ± 0.10**
 D = **1.25 ± 0.10**
 I = **1.25 ± 0.20**
 C = **0.95 ± 0.10**
 J = **1.15 ± 0.15**

P = **1.60+0.30/-0.10**
 K = **2.00 ± 0.20**
 M = **2.50 ± 0.30**
 U = **2.80 ± 0.30**
 V = **2.00± 0.20 or 2.50 ± 0.50**
 L = **0.30 ± 0.03**
 T = **0.85 ± 0.10**
 G = **1.6 ± 0.20**